

Single Line Bi-directional Transient Voltage Suppressor

DESCRIPTION

The GSD4V5TC TVS diode is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebooks, and PDA's. It offers superior electrical characteristics such as low clamping voltage, low leakage current and high surge capability. It is designed to protect sensitive electronic components which are connected to power lines, from over-stress caused by ESD (Electrostatic Discharge), EFT (Electrical Fast Transients) and Lighting.

The GSD4V5TC is in a SOD-323 package and will protect one unidirectional line. It may be used to provide ESD protection up to $\pm 30 \text{kV}$ (Contact and air discharge) according to IEC61000-4-2 , and withstand peak pulse current up to 160A (8/20µs) according to IEC61000-4-5.

ORDERING INFORMATION

Device: GSD4V5TCPackage: SOD-323

♦ Marking: D4

♦ Material: Halogen free and RoHS compliant

→ Packing: Tape & Reel→ Quantity per reel: 3,000pcs

FEATURES

♦ Transient protection for high-speed data lines IEC 61000-4-2 (ESD) ±30kV (Contact)

±30kV (Air)

♦ Peak power dissipation: 3200W (8/20µs)

♦ Working voltages : 4.5V

♦Low leakage current

♦Low clamping voltage

♦ Solid-state silicon-avalanche technology

MACHANICAL DATA

♦SOD-323 package

♦ Flammability Rating: UL 94V-0

♦ High temperature soldering guaranteed: 260°C/10s

♦ Packaging: Tape and Reel

♦Reel size: 7 inch

APPLICATIONS

♦Power lines

♦ Personal digital assistants (PDA's)

♦ Microprocessors based equipment

♦Notebooks, Desktops, and Servers

♦ Cell phone Handsets and Accessories

♦ Portable Electronics

♦ Peripherals

PIN CONFIGURATION



PACKAGE OUTLINE





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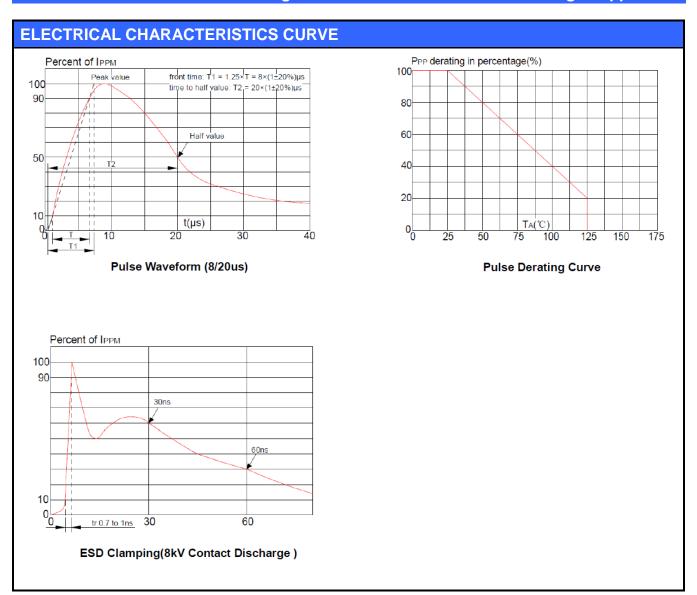
ABSOLUTE MAXIMUM RATING								
Symbol	Parameter	Value	Units					
V _{ESD}	ESD per IEC 61000-4-2 (Contact) ESD per IEC 61000-4-2 (Air)	±30 ±30	kV					
P _{PP}	Peak Pulse Power (8/20μs)	3200	W					
T _{OPT}	Operating Temperature	-55~125	°C					
T _{STG}	Storage Temperature	-55~150	°C					
TL	Lead Soldering Temperature	260(10sec)	°C					

ELECTRICAL CHARACTERISTICS (Tamb=25°C)							
Symbol	Parameter	Test Condition	Min	Тур	Max	Units	
V _{RWM}	Reverse Working Voltage				4.5	V	
V_{BR}	Reverse Breakdown Voltage	I _T = 1mA	4.6	5.2	6.4	V	
I _R	Reverse Leakage Current	$V_{RWM} = 4.5V$			1	uA	
I _{PP}	Peak Pulse Current	t _p = 8/20µs			160	А	
Vc	Clamping Voltage	$I_{PP} = 50A, t_p = 8/20\mu s$		8.5	11	V	
		$I_{PP} = 100A, t_p = 8/20\mu s$		12	14	V	
		$I_{PP} = 160A, t_p = 8/20\mu s$		17	20	V	
CJ	Junction Capacitance	$V_R = 0V$, $f = 1MHz$		300	500	pF	

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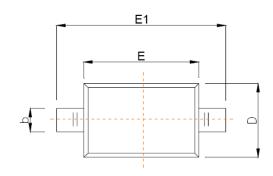


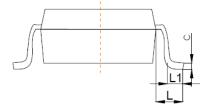
REV: A 3 of 4 www.gt-semi.com

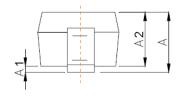


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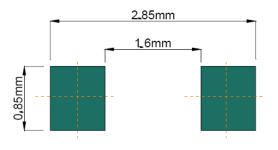
SOD-323 PACKAGE OUTLINE DIMENSIONS







	Dimensions In Millimeters		
Symbol	Min	Max	
А		1.00	
A1	0.000	0.100	
A2	0.800	0.900	
b	0.250	0.350	
С	0.080	0.150	
D	1.200	1.400	
E	1.600	1.800	
E1	2.500	2.700	
е	1.800	2.040	
L	0.475 REF		
L1	0.250	0.400	
θ	0°	8°	



Recommended Pad outline